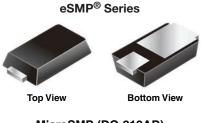
VS-1EQH01HM3, VS-1EQH02HM3

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Ultrafast Rectifier, 1 A FRED Pt[®]



MicroSMP (DO-219AD)

Anode O Cathode

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)} 1 A				
V _R	100 V, 200 V			
V _F at I _F	0.72 V			
t _{rr} (typ.)	33 ns			
I _{FSM}	30 A			
T _J max.	175 °C			
Package	MicroSMP (DO-219AD)			
Circuit configuration	Single			

FEATURES

- · Very low profile typical height of 0.65 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- AEC-Q101 qualified
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

MECHANICAL DATA

Case: MicroSMP (DO-219AD)

Molding compound meets UL 94 V-0 flammability rating Terminals: matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Dook ropotitivo rovoroo voltago	VS-1EQH01HM3	V		100	V		
Peak repetitive reverse voltage	VS-1EQH02HM3	V _{RRM}		200	v		
Average rectified forward current		I _{F(AV)}	T _M = 159 °C	1	•		
Non-repetitive peak surge current		I _{FSM}	$T_J = 25 \ ^{\circ}C$, 10 ms sine pulse	30	A		
Operating junction and storage temperatures		TJ, T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage,	VS-1EQH01HM3	V _{BR} ,	I _R = 100 μA	100	-	-	v
blocking voltage	VS-1EQH02HM3	V _R		200			
Forward voltage		V _F	I _F = 1 A	-	0.88	0.97	
Forward voltage			I _F = 1 A, T _J = 150 °C	-	0.72	0.75	
Reverse leakage current		I _R	$V_{R} = V_{R}$ rated	-	-	1	μA
			$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	25	
Junction capacitance		CT	V _R = 200 V	-	6	-	pF

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RoHS

COMPLIANT HALOGEN

FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS MIN. TYP.			MAX.	UNITS
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	33	-	
Reverse recovery time	t _{rr}	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	23	
		T _J = 25 °C		-	13	-	ns
		T _J = 125 °C		-	18	-	
Poole recovery ourrent	1	T _J = 25 °C	l _F = 1 A dl _F /dt = 200 A/μs V _R = 100 V	-	1.8	-	A
Peak recovery current	IRRM	T _J = 125 °C		-	2.7	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	11	-	nC
		T _J = 125 °C		-	23	-	10

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to mount		R _{thJM} ⁽¹⁾		-	16	20	
Thermal resistance, junction to ambient		R _{thJA}	Device mounted on FR4 PCB, 2 oz. standard footprint	-	160	-	°C/W
Approximate weight					0.006		g
Marking device VS-1EQH01HM3 VS-1EQH02HM3			Case style MicroSMP (DO-219AD)	1H1			
			Case style MicroSMP (DO-219AD) 1H2		-12		

Note

⁽¹⁾ Thermal resistance junction to mount follows JEDEC[®] 51-14 transient dual interface test method (TDIM)

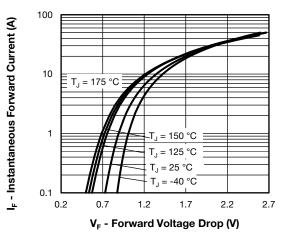


Fig. 1 - Typical Forward Voltage Drop Characteristics

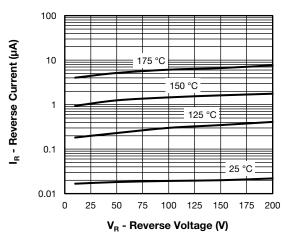


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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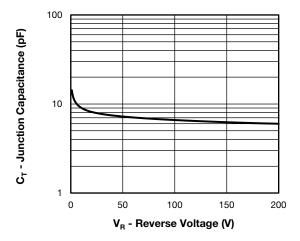


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

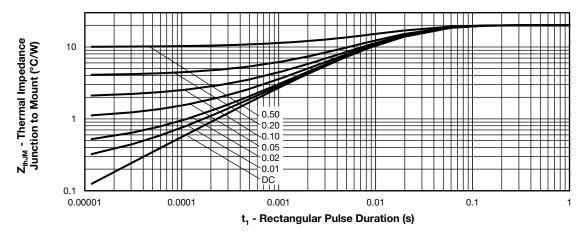
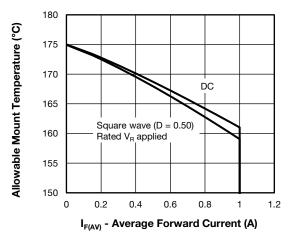
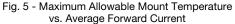


Fig. 4 - Maximum Transient Thermal Impedance, Junction to Mount







Formula used: $T_M = T_J - (Pd + Pd_{REV}) \times R_{thJM}$; Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = rated V_R

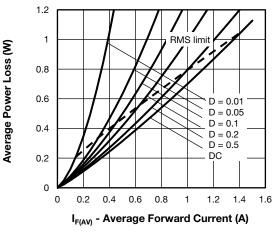


Fig. 6 - Forward Power Loss Characteristics

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VS-1EQH01HM3, VS-1EQH02HM3

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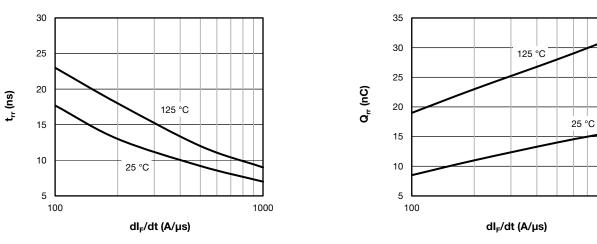


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

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Fig. 8 - Typical Stored Charge vs. dl_F/dt

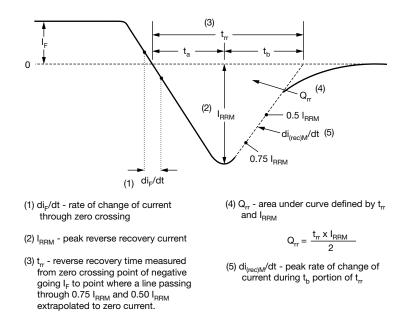
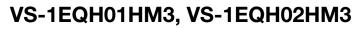


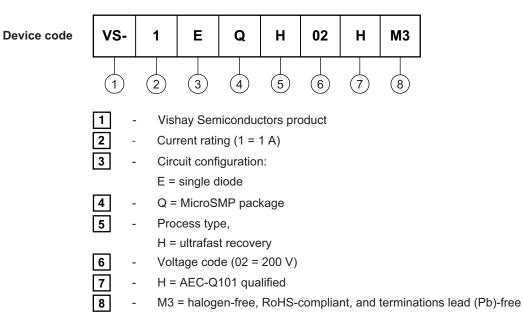
Fig. 9 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)							
PREFERRED P/N PREFERRED PACKAGE CODE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-1EQH01HM3/H	Н	4500	7" diameter plastic tape and reel				
VS-1EQH02HM3/H	Н	4500	7" diameter plastic tape and reel				

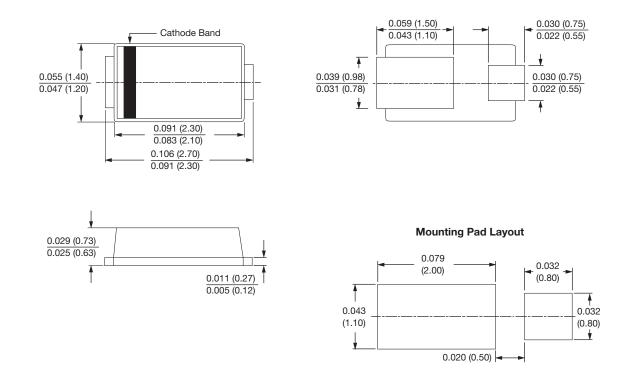
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96591</u>				
Part marking information	www.vishay.com/doc?96590			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96594			



Vishay Semiconductors

MicroSMP (DO-219AD), FRED Pt®

DIMENSIONS in inches (millimeters)





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